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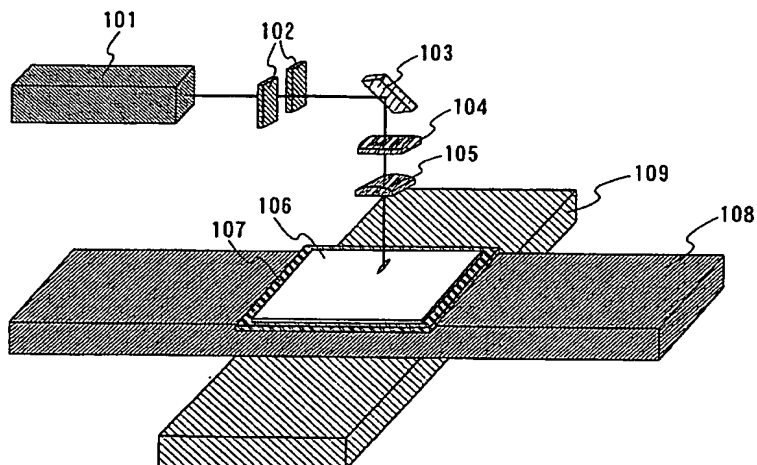
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ning of each regular issue of the PCT Gazette.

(54) Title: LASER IRRADIATION METHOD AND LASER IRRADIATION APPARATUS



(57) Abstract: An object of the present invention is to provide a laser irradiation method and a laser irradiation apparatus for irra-
diating an irradiation surface with a linear beam having more homogeneous intensity by blocking a low-intensity part of the linear
beam without forming the fringes due to the diffraction on the irradiation surface. In the laser irradiation, a laser beam emitted from
a laser oscillator 101 passes through a slit 102 so as to block a low-intensity part of the laser beam, the traveling direction of the laser
beam is bent by a mirror 103, and an image formed at the slit is projected to an irradiation surface 106 by a convex cylindrical lens
104.